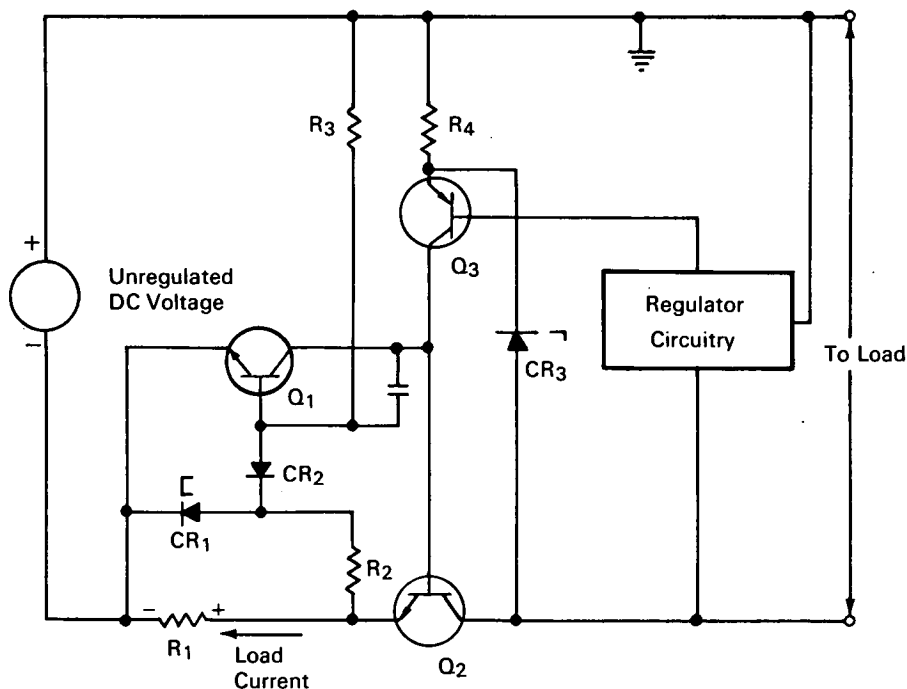


NASA TECH BRIEF



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Circuit Protects Regulated Power Supply Against Overload Current



The problem:

To protect a low voltage transistorized dc regulator from damage by excessive load currents. In some applications, a single load fault can disable an entire system by disabling the regulators. Current threshold detectors have employed zener diodes and the voltage characteristics of transistor base-emitter junctions but these have not achieved sharp detection and current limiting.

The solution:

A sensing circuit in which a tunnel diode controls a series regulator transistor. When a fault occurs, the

faulty circuit is limited to a preset percentage of the current when limiting first occurs.

How it's done:

R_4 , Q_3 , and CR_3 form the regulator series stage driver and Q_2 is the regulator series element. The overload circuit is composed of R_1 , R_2 , R_3 , CR_1 , CR_2 , and Q_1 , and functions by shunting the base current of Q_2 through Q_1 in case of overload, thereby shutting off Q_2 and limiting the fault current. The volt-ampere characteristics of CR_1 are used to provide the voltage threshold detection. The voltage across R_1 is used to detect the magnitude of the load current.

(continued overleaf)

When the load current is just below the limiting level, current through R_3 plus current through R_2 is just below the threshold point of CR_1 . The base-to-emitter voltage of Q_1 is the sum of voltages across CR_1 and CR_2 and the current through R_3 is such that the voltage across CR_2 is about 400 mv. The voltage across CR_1 is at 50 mv and the base-emitter voltage of Q_1 is 450 mv which is not sufficient to turn on Q_1 . This is the normal mode of overload circuit/regulator function.

When the load current causes the peak-point current of CR_1 to be exceeded, it causes the base-emitter voltage of Q_1 to turn that transistor on. As a result, current through R_3 now flows into the base of Q_1 and the collector current of Q_3 flows into Q_1 rather than the base of Q_2 so that Q_2 turns off and limits the current to the regulator, the collector-emitter (saturated) voltage of Q_1 being less than the threshold base-emitter voltage of Q_2 . The regulator series element being turned off, current through R_1 decreases, allowing current through CR_1 to decrease. When the current through CR_1 drops below its valley-point current, the overload circuit returns to its original state. If the overload is still present, the cycle is repeated, alternately cutting off Q_2 and continuing to limit overload current to the regulator until the fault in the load is corrected. Value of the capacitor controls frequency of the series stage cycle.

Notes:

1. Typical changes of the threshold detection current are $\pm 10\%$ over a range from 0° to $+70^\circ\text{C}$. Any change with temperature in the base-emitter voltage threshold of Q_1 is compensated for by a like change in the threshold voltage of CR_2 .
2. This circuit provides sharp detection of overload currents at very low voltage levels and has limited short circuit currents to less than 10% more than the detector (CR_1) threshold current.
3. The circuit shown uses a germanium tunnel diode but will perform satisfactorily with one of silicon.
4. Inquiries concerning this innovation may be directed to:

Technology Utilization Officer
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Greenbelt, Maryland 20771
Reference: B66-10292

Patent status:

No patent action is contemplated by NASA.

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